The Effect of substrate Nature on the properties of Tin Sulfide Nanostructured Films Prepared by chemical bath deposition

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Abstract

The substrate’s nature plays an important role in the characteristics of semiconductor films because of the thermal and lattice mismatching between the film and the substrate. In this study, tin sulfide (SnS) nanostructured thin films were grown on different substrates (polyester, glass, and silicon) using a simple and low-cost chemical bath deposition technique. The structural, morphological, and optical properties of the grown thin films were investigated using X-ray diffraction (XRD), field emission scanning electron microscopy (FESEM), and ultraviolet-visible-near infrared (UV-Vis-NIR) spectroscopy. The XRD and FESEM results of the prepared films revealed that each film is polycrystalline and exhibits both orthorhombic and cubic structure types. In addition, the deposited films on polyester and glass showed good absorption in the UV-Vis-NIR range.

Keywords: Tin sulfide; Chemical bath deposition; Polyester; glass, nanostructure.

1. Introduction

Recently, significant attempts have been made to synthesize and characterize nanostructured semiconductor materials owing to their unique properties, as well as their performance in a variety of applications, notably sensing, i.e., their ability to sense gas and light [1]. Researchers are increasingly interested in IV-VI semiconductors such as SnS, GeSe, and PbS because of their numerous applications, such as photovoltaic devices and near-infrared detectors [2]. Among these semiconductors, SnS has advantages, including abundance, low toxicity, and a high absorption coefficient (10^4 cm^-1) [3–5]. SnS nanostructure films can be deposited through different techniques, such as electrodeposition [6], spray pyrolysis [7], radio frequency sputtering [8],
thermal evaporation [9], and chemical bath deposition (CBD) [10-14]. The CBD technique is simple, low-cost, and uses low-temperature deposition (<100 °C) compared to other techniques. Additionally, it can be used for continuous deposition. Moreover, the substrate's nature plays a crucial role in the characteristics of SnS film because of the thermal and lattice mismatching between the film and the substrate. Therefore, in this work, the nanostructured SnS films were deposited using the CBD method on different substrates (polyester, glass, and silicon).

2. Experimental part

The CBD technique was used to synthesize SnS films on different substrates (glass, polyester, and Si). The procedure consists of 1.12 g dihydrate tin chloride, 3.234 g complex agent tri-sodium citrate, and 0.56 g thiocetamide. All chemical materials were dissolved in 50 ml of deionized water. Aqueous ammonia was added drop by drop, and the pH of the solution was adjusted to 6.5. The mixture was stirred well using a magnetic stirrer at room temperature. Substrates were ultrasonic cleaned in acetone, methanol, and deionized water, respectively, for 30–40 minutes before film deposition. Then, the substrates were immersed in the mixture. The deposition was carried out at 80 °C for 4 h. The substrates were removed from the beaker, washed with deionized water, and dried naturally. The structural, morphological, and optical properties of the grown thin films were examined using X-ray diffraction (XRD), field emission scanning electron microscopy (FESEM), and ultraviolet-visible-near infrared (UV-Vis-NIR) spectroscopy.

3. Results and discussion

3.1 Structural properties

Figure 1 shows the X-ray diffraction patterns of grown SnS films on polyester, glass, and silicon substrates. These patterns showed two peaks in the area around 2θ = 31.9 and 39.7, which can be indexed to the orthohombic structure of SnS (ICDD Card: 39-0354) [4, 5, 15]. Moreover, the XRD patterns of the deposited films on the glass and silicon substrates exhibit additional peaks around 2θ = 26.85 and 31.1, which can be indexed to the cubic structure of SnS [15, 16]. In addition, the peaks of polyester, and silicon substrates were observed. The high, intense, and wide peak of the polyester substrate at 2θ = 26.3˚ may be responsible for the absence of peaks of the cubic structure in the pattern of the deposited film on polyester.

The average crystalline size (D) was calculated from the XRD pattern using Scherrer’s formula, which is expressed as follows [5, 17, 18]:
where $\lambda$ is the x-ray wavelength, $\beta$ is the full width at half maximum of the XRD peak, and $\theta$ is the Bragg angle. The $D$ values for (111) orientation were found to be 223 Å, 172 Å, and 295 Å for deposited films on glass, Si, and polyester, respectively. The strain ($\epsilon$) values of the grown films were calculated using the following equation [19]:

$$\epsilon = \frac{\beta}{4\tan\theta}$$

The $\epsilon$ values for (111) orientation are 5.64 x 10^{-3}, 7.34 x 10^{-3}, and 4.24 x 10^{-3} for grown films on glass, Si, and polyester, respectively. Comparative analysis of the XRD findings for the films is shown in Table 1.

**Table 1:** XRD findings of deposited SnS films on different substrates.

<table>
<thead>
<tr>
<th>Substrate</th>
<th>(h k l)</th>
<th>D (Å)</th>
<th>$\epsilon \times 10^{-3}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Polyester</td>
<td>(111)</td>
<td>295</td>
<td>4.24</td>
</tr>
<tr>
<td>Glass</td>
<td>(111)</td>
<td>223</td>
<td>5.64</td>
</tr>
<tr>
<td>Silicon</td>
<td>(111)</td>
<td>172</td>
<td>7.34</td>
</tr>
</tbody>
</table>

### 3.2 Surface Morphology

**Figure 2** shows FESEM images of deposited films on various substrates. It is obvious that the grown films on polyester and glass substrates comprise many flower-like nanostructures agglomerating for SnS orthorhombic structure, as well as beneath a layer of spherical grains for cubic SnS [16, 20, 21]. While the grown film on the glass substrate comprised distributed and uniformly many flower-like nanostructures for orthorhombic structure SnS, as well as a beneath layer of spherical grains for cubic SnS. The presence of two morphologies that relate to orthorhombic and cubic structures agrees with the XRD analysis of **Figure 1**.
3.3 Optical properties

The absorbance spectra of deposited films on polyester and glass substrates in the range of (350 - 1100 nm) are shown in Figure (3). According to the spectra, the absorption in the visible and near-infrared wavelengths is generally good. Additionally, the deposited film on glass has a larger absorbance value than the film on polyester in the range of (550 - 1100 nm). While the spectra behave differently in the range of (350 - 550 nm), the film deposited on polyester has a higher absorbance value than the film deposited on glass.

![Figure 3](image1.png)

**Figure 3.** The absorbance spectra of deposited films on polyester and glass substrates.

The nature of the energy gap optical transmission can be determined using the relation [5, 22]:

$$\alpha h\nu = A(h\nu - E_g)^n$$

(3)

where $A$ is constant, $h$ is Planck constant, $\nu$ denotes frequency, $E_g$ is the energy gap, and $\alpha$ is absorption coefficient. Figure (4) illustrates plotting $(\alpha h\nu)^2$ versus $(h\nu)$ curves for films deposited on two different substrates. The equation (3) is matched with $n = 1/2$, which indicates permissible transitions. The $E_g$ value can be determined by extrapolating the straight line of $(\alpha h\nu)^2$ versus the $h\nu$ curve to intercept the horizontal $h\nu$ axis. From Figure (4), the $E_g$ values were found to be 1.38 and 1.02 eV for grown films on polyester and glass substrates, respectively.

![Figure 4](image2.png)

**Figure 4.** Energy gap of grown films on (a) polyester (b) glass
4. Conclusion

In this work, the nanostructure of tin sulfide (SnS) thin films was successfully grown by simple and low-cost chemical bath deposition on different polyester, glass, and silicon substrates. The obtained results showed that the substrate nature had significant effects on the structural, morphological, and optical properties of the deposited films.

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References


